TLV4906L

Value Optimized Hall Effect Switch for Industrial and Consumer ApplicationsHigh Precision Hall Effect Switch

About this document

Overview

The TLV4906L is a high precision Hall Effect Switch with highly accurate switching thresholds for ambient operating temperatures up to 85°C.

Features

- 2.7 V to 18 V supply voltage operation.
- Operation from unregulated power supply.
- High sensitivity and high stability of the magnetic switching points.
- High resistance to mechanical stress by active error compensation.
- Reverse battery protection (-18 V).
- Superior temperature stability.
- Low jitter (typically 1 µs).
- High ESD performance (± 4 kV HBM).
- Digital output signal (open-drain).
- Not suitable for automotive applications

Target applications

The TLV4906L is ideally suited for all industrial and consumer applications that require a high precision switching thresholds for position sensing. It can be used for example for: security systems, alignment control, push buttons, keyboards, key switches, machine tools, etc.

Product name	Product type	Ordering code	Package
TLV4906L	Hall Effect Switch	SP000604324	PG-SSO-3-2

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1 Functional description

1.1 General

Precise magnetic switching thresholds and high temperature stability are achieved by active compensation circuits and chopper techniques on chip. Offset voltages generated by temperature-induced stress or overmolding are canceled so that high accuracy is achieved. The IC has an open collector output stage with 20 mA current sink capability. A wide operating voltage range from 2.7 V to 18 V with reverse polarity protection down to -18 V makes the TLV4906L suitable for a wide range of applications. A magnetic south pole with a field strength above Bop turns the output transistor on (output voltage low) and for a magnetic field below Brp the output transistor is switched off (output voltage high).

1.2 Pin configuration

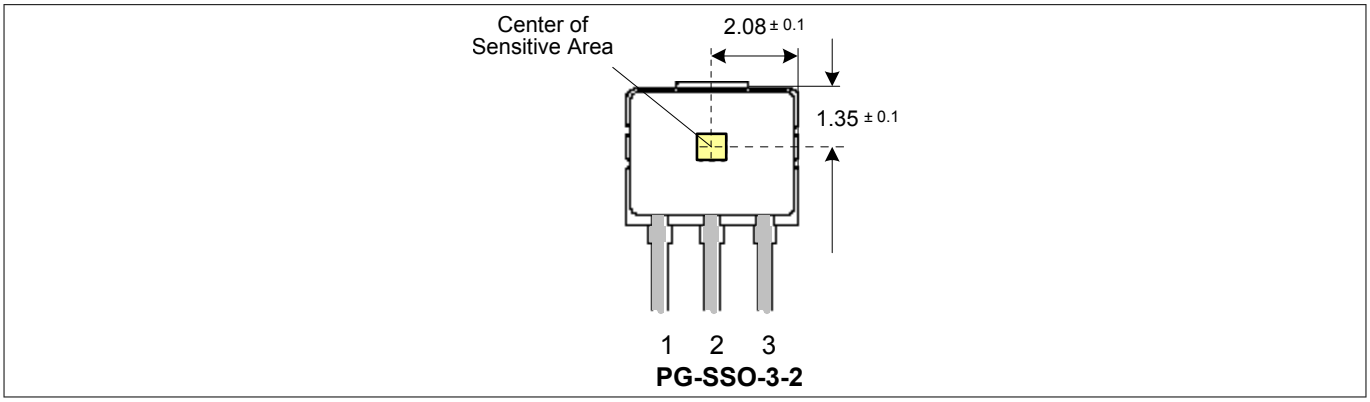

Figure 1 Pin configuration and sensitive area (Top view, figure not to scale)

1.3 Pin description

Table 1 Pin Definitions for the PG-SSO-3-2 package

Pin No.	Name	Function
1	V_S	Supply Voltage
2	*GND*	Ground
3	*Q*	Output

1.4 Block diagram

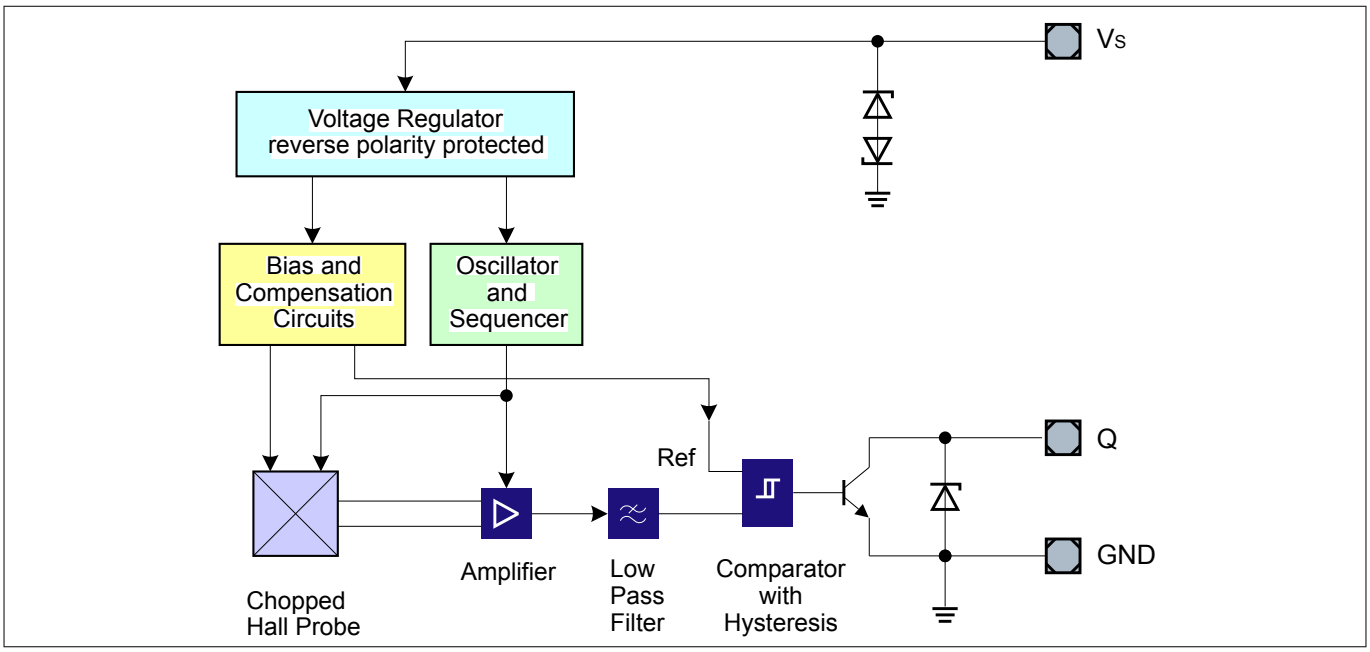

Figure 2 TLV4906L Block Diagram

1.5 Operating modes and states

Field direction and definition

Positive magnetic fields correspond to the south pole of the magnet targeting the branded side of the package.

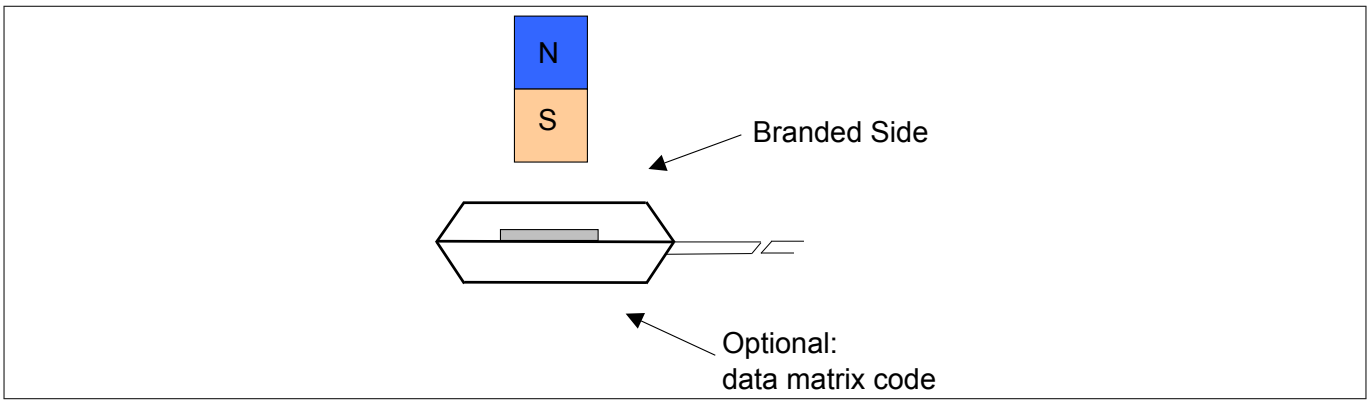

Figure 3 Definition of the magnetic field direction

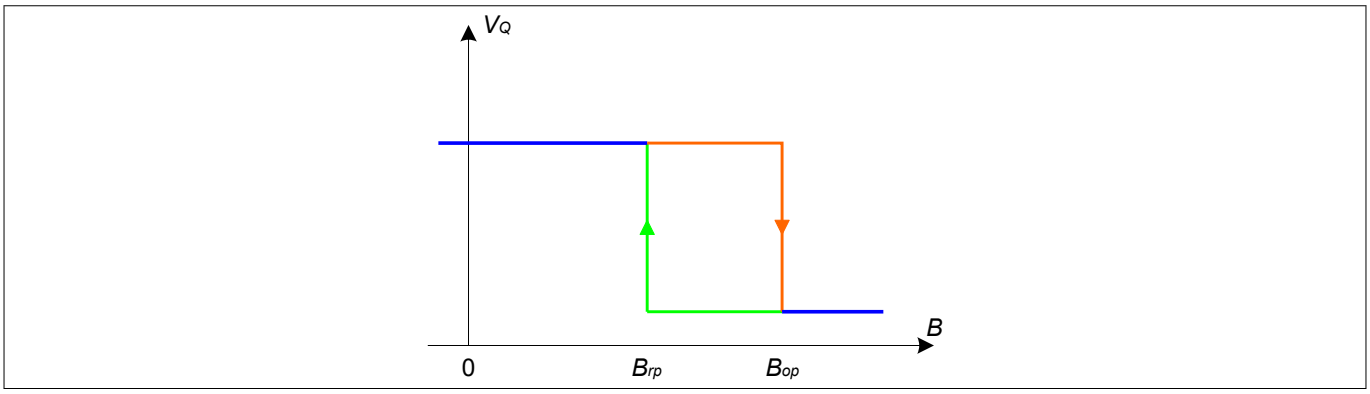

Figure 4 Output signal

1.6 Functional block description

The chopped Hall Effect Switch comprises a Hall probe, a bias generator, compensation circuits, an oscillator and an output transistor. The bias generator provides currents to the Hall probe and the active circuits. Compensation circuits stabilize response of the IC over temperature and reduce the impact of process variations. The Active Error Compensation rejects offsets in the signal path and reduces the impact of mechanical stress in the package caused by molding, soldering and thermal effects. The chopper technique together with the threshold generator and the comparator ensure high accurate magnetic switching points.

2 Specification

2.1 Application circuit

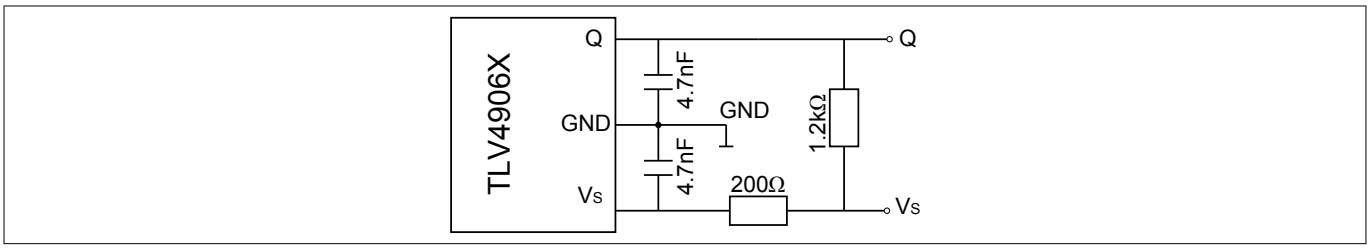

Figure 5 Application circuit

It is recommended to use a resistor of 200 Ω in the supply line for current limitation in the case of an overvoltage pulse. Two capacitors of 4.7 nF enhance the EMC performance. The pull-up of 1.2 kΩ limits the current through the output transistor.

2.2 Absolute maximum ratings

Stress above the maximum values listed in this section may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect the reliability of the device. Exceeding only one of these values may cause irreversible damage to the device.

Table 2 Absolute maximum ratings

Parameter	Symbol	Values			Unit	Note/Test Condition
		Min.	Typ.	Max.		
Maximum Ambient Temperature	T_A	-40	–	125	°C	
Maximum Junction Temperature	T_J	-40	–	150	°C	
Supply Voltage	V_S	-18	–	18	V	
Supply current through protection device	I_S	-50	–	50	mA	
Output Voltage	V_{OUT}	-0.7	–	18	V	
Storage Temperature	T_S	-40	–	150	°C	
Magnetic flux density	B	–	–	unlimited	mT	
ESD Robustness HBM: 1.5 kΩ, 100 pF	$V_{ESD,HBM}$ (1)	–	–	4	kV	

(1) According to EIA/JESD22-A114-E

2.3 Operating range

The following operating conditions must not be exceeded in order to ensure correct operation of the TLV4906L. All parameters specified in the following sections refer to these operating conditions unless otherwise mentioned.

Table 3 Operating range

Parameter	Symbol	Values			Unit	Note/Test Condition
		Min.	Typ.	Max.		
Supply Voltage	V_S	2.7	–	18	V	
Output Voltage	V_Q	-0.7	–	18	V	
Output Current	I_Q	0	–	20	mA	
Maximum Ambient Temperature	T_A	-40	–	85	°C	

2.4 Electrical characteristics

Product characteristics include the spread of values guaranteed within the specified voltage and ambient temperature range. typical characteristics are the median of the production (at V_S = 12 V and T_A = 25°C).

Table 4 Electrical characteristics

Parameter	Symbol	Values			Unit	Note or Test Condition
		Min.	Typ.	Max.		
Supply Current	I_S	2	4	6	mA	V_S = 2.7 V … 18 V
Reverse Current	I_{SR}	0	0.2	1	mA	V_S = -18 V
Output Saturation Voltage	V_{QSAT}	–	0.3	0.6	V	I_Q = 20 mA
Output leakage current	*IQLEAK*	–	0.05	10	µA	V_Q = 18 V
Output fall time(1)	t_f	–	0.02	1	µs	R_L = 1.2 kΩ, C_L = 50 pF
Output rise time(1)	t_r	–	0.4	1	µs	
Chopper frequency	f_{OSC}	–	320	–	kHz	
Switching frequency	f_{SW}	0	–	15(2)	kHz	
Delay time(3)	t_d	–	13	–	µs	
Output jitter(4)	t_{QJ}	–	1	–	$µs_{RMS}$	Typical value for a 1 kHz square wave signal
Power-on Time(5)	t_{PON}	–	13	–	µs	V_S > 2.7 V
Thermal Resistance junction to ambient(6)	R_{thJA}	–	–	190	K/W	TLV4906L

(1) See ***Figure 6***
(2) To operate the sensor at maximum switching frequency, the value of the magnetic signal amplitude must be 1.4 times higher than the static fields. This is due to the -3 dB corner frequency of the low pass filter in the signal path.
(3) Systematic delay between magnetic threshold reached and output.
(4) Jitter is the unpredictable deviation of the output switching delay.
(5) Time from applying V_S > 2.7 V to the sensor until the output state is valid.
(6) Relationship between junction and ambient temperature: $T_J = T_{amb} + R_{thja} . (V_S . I_S + V_{QS} . I_Q)$.

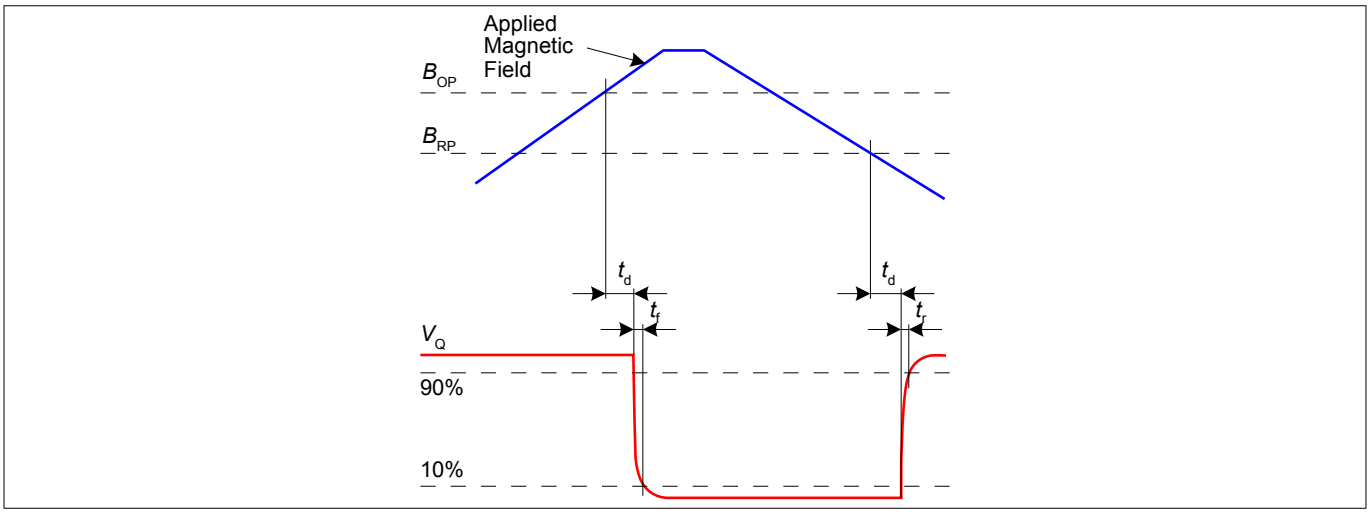

Figure 6 Timing diagram

Table 5 Magnetic characteristics(1)

Parameter	Symbol	Values			Unit	Note/Test Condition
		Min.	Typ.	Max.		
Operate point	B_{OP}	6.2	10.0	13.9	mT	
Release point	B_{RP}	4.7	8.5	12.3	mT	
Hysteresis	B_{HYS}	0.7	1.5	3.0	mT	(2)
Temperature compensation of magnetic thresholds	*TC*	–	-350	–	ppm/°C	
Repeatability of magnetic thresholds(3) B_{REP} is equivalent to the noise constant.	B_{REP}	–	20	–	μT_{RMS}	typical value for $\Delta B/\Delta t > 12$ mT/ms

(1) Over all operating conditions.
(2) At 25°C.
(3)

3 Package information

3.1 TLV4906L Package outline

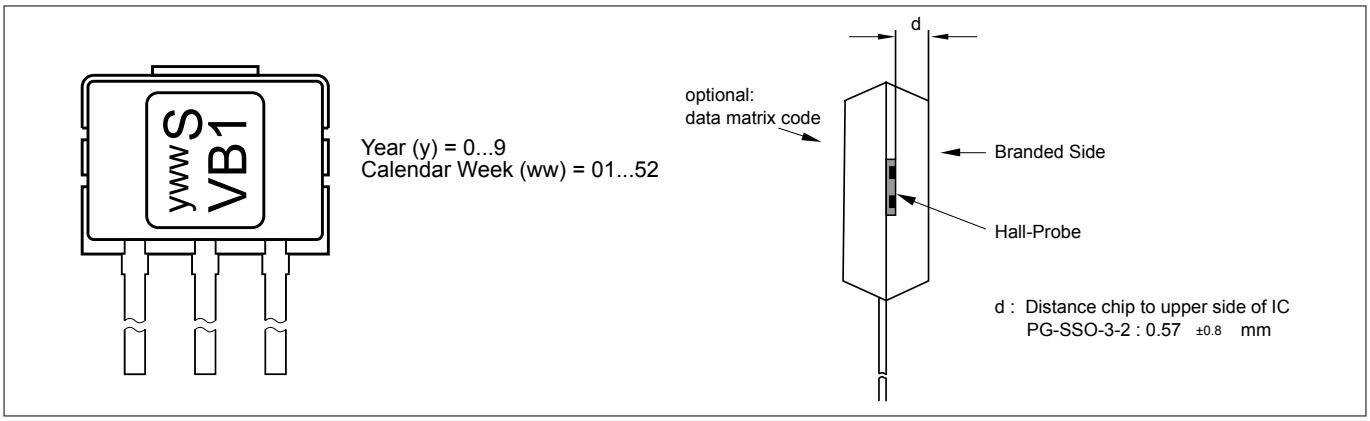

Figure 7 Marking of the TLV4906L and distance of the chip to the upper side

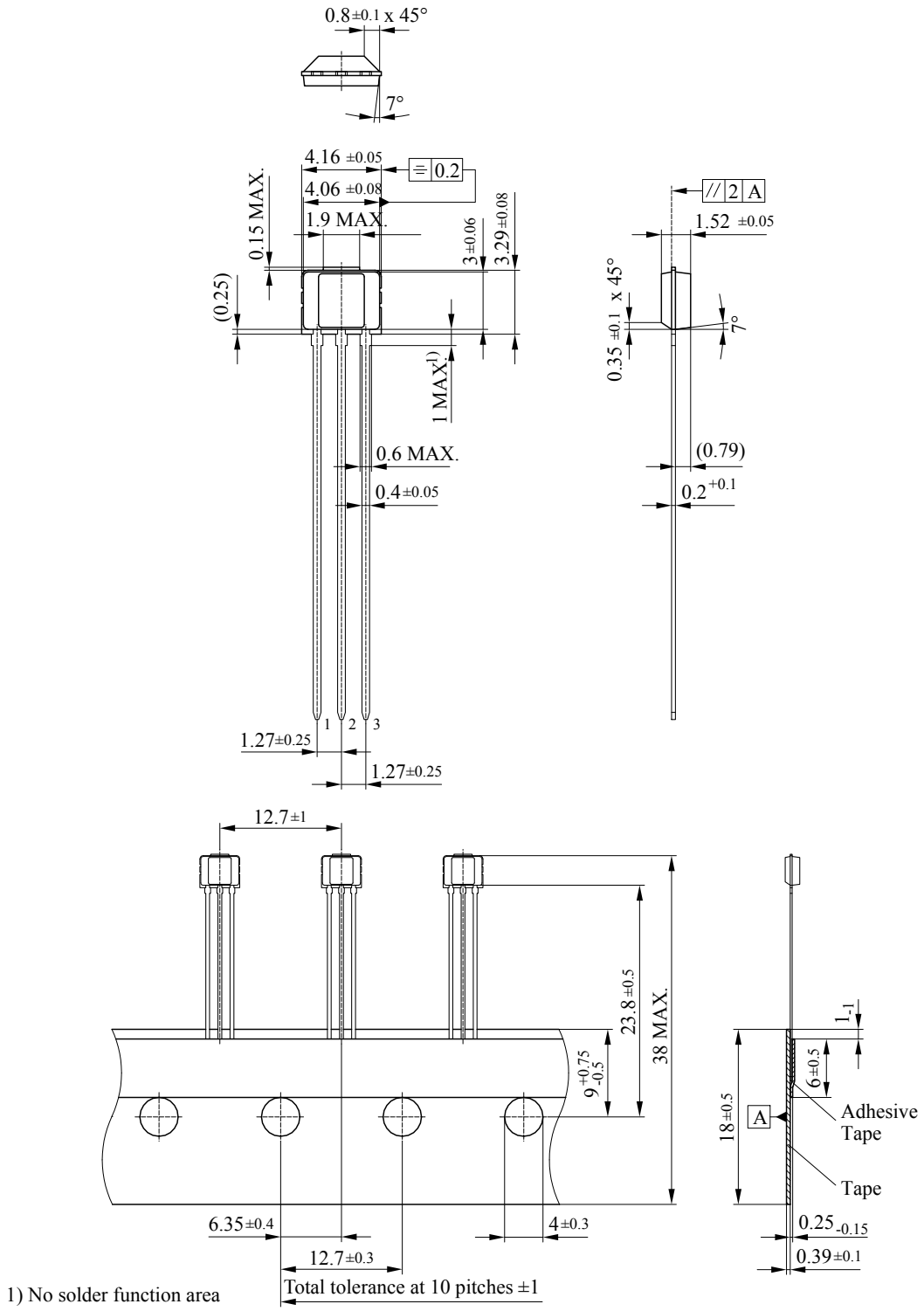

Figure 8 PG-SSO-3-2 Package outline

4 Revision history

Revision History	
Page	**Subjects (major changes since last revision)**
Revision History: 2020-08, Rev. 1.2	
Previous Revisions: 1.1	
9	Edited figure 7 (optional: data matrix code)

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